# NL17SZ08E

# **Single 2-Input AND Gate**

The NL17SZ08E is a single 2–input AND Gate in three tiny footprint packages. The device performs much as LCX multi–gate products in speed and drive. They should be used wherever the need for higher speed and drive are needed.

#### Features

- Tiny SOT-353 Package
- 2.7 ns T<sub>PD</sub> at 5.0 V (typ)
- Source/Sink 24 mA at 3.0 V
- Overvoltage Tolerant Inputs
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

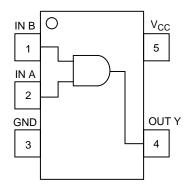


Figure 1. Pinout (Top View)

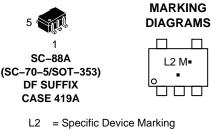


Figure 2. Logic Symbol



### **ON Semiconductor®**

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- M = Date Code\*
- = Pb–Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

#### PIN ASSIGNMENT

Pin	Function
1	IN B
2	IN A
3	GND
4	OUT Y
5	V <sub>CC</sub>

#### FUNCTION TABLE

Ing	Output Y = AB	
Α	В	Y
L	L	L
L	н	L
Н	L	L
Н	Н	Н

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

## **NL17SZ08E**

#### **MAXIMUM RATINGS**

Symbol	Parameter		Value	Units
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
V <sub>OUT</sub>	DC Output Voltage	Active Mode, High or LOW State Power Down Mode (V <sub>CC</sub> = 0 V)	–0.5 to V <sub>CC</sub> + 0.5 –0.5 to +6.5	V
I <sub>IK</sub>	DC Input Diode Current		-50	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-50	mA
I <sub>OUT</sub>	DC Output Sink Current		±50	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin		±100	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{JA}$	Thermal Resistance	(Note 1)	350	°C/W
PD	Power Dissipation in Still Air at 85°C		186	mW
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD	ESD Classification	Human Body Model (Note 2) Charged Device Model (Note 3)	4000 1000	V
ILATCHUP	Latchup Performance Above $V_{CC}$ and Below GND at 1	25°C (Note 4)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.

Tested to JESD22–C101–A.
Tested to EIA/JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Max	Units
V <sub>CC</sub>	DC Supply Voltage		1.65	5.5	V
V <sub>IN</sub>	DC Input Voltage		0	5.5	V
V <sub>OUT</sub>		tive Mode, LOW State own Mode ( $V_{CC} = 0 V$ )	0 0	V <sub>CC</sub> 5.5	V
T <sub>A</sub>	Operating Temperature Range		-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	$V_{CC} = 2.5 V \pm 0.3 V V_{CC} = 3.0 V \pm 0.3 V V_{CC} = 5.0 V \pm 0.5 V$	0 0 0	20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

			V <sub>cc</sub>	T,	<sub>A</sub> = 25°	С	–55°C ≤ T <sub>A</sub> ≤ 125°C		
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
V <sub>IH</sub>	High–Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>			0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>		0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>	V
V <sub>OH</sub>	High–Level Output Voltage	I <sub>OH</sub> = -100 μA	1.65 to 5.5	V <sub>CC</sub> – 0.1	V <sub>CC</sub>		V <sub>CC</sub> – 0.1		V
	$V_{IN} = V_{II}$ or $V_{IH}$	I <sub>OH</sub> = -4 mA	1.65	1.29	1.52		1.29		
		$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.1		1.9		
		I <sub>OH</sub> = -12 mA	2.7	2.2	2.4		2.2		
		I <sub>OH</sub> = -16 mA	3.0	2.4	2.7		2.4		
		I <sub>OH</sub> = -24 mA	3.0	2.3	2.5		2.3		
		$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.0		3.8		
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OL</sub> = 100 μA	1.65 to 5.5			0.1		0.1	V
	$V_{IN} = V_{IH} \text{ or } V_{OH}$	$I_{OL} = 4 \text{ mA}$	1.65		0.08	0.24		0.24	
		I <sub>OL</sub> = 8 mA	2.3		0.20	0.3		0.3	
		I <sub>OL</sub> = 12 mA	2.7		0.22	0.4		0.4	
		I <sub>OL</sub> = 16 mA	3.0		0.28	0.4		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.38	0.55		0.55	
		I <sub>OL</sub> = 32 mA	4.5		0.42	0.55		0.55	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	1.65 to 5.5			±0.1		±1.0	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = 5.5 V or GND	5.5			1		10	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0			1		10	μΑ

#### DC ELECTRICAL CHARACTERISTICS

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# NL17SZ08E

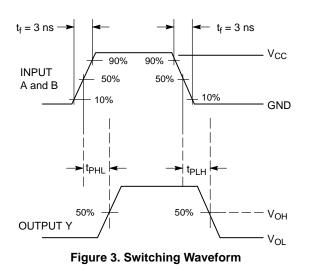
			Vcc		T <sub>A</sub> = 25°C	;	–55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
t <sub>PLH</sub>	Propagation Delay	$R_L = 1 M\Omega, C_L = 15 pF$	1.65		6.3	12		12.7	ns
t <sub>PHL</sub>	(Figure 3 and 4)	$R_L = 1 M\Omega, C_L = 15 pF$	1.8		6.2	10		10.5	
		$R_L = 1 M\Omega, C_L = 15 pF$	$2.5\pm0.2$		3.4	7.0		7.5	
		$R_L = 1 M\Omega, C_L = 15 pF$	$3.3\pm0.3$		2.6	4.7		5.0	
		$R_L = 500 \ \Omega, C_L = 50 \ pF$			3.3	5.2		5.5	
		$R_L = 1 M\Omega, C_L = 15 pF$	$5.0\pm0.5$		2.2	4.1		4.4	
		$R_L = 500 \ \Omega, C_L = 50 \ pF$			2.7	4.5		4.8	

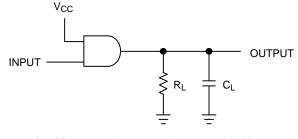
### AC ELECTRICAL CHARACTERISTICS $t_R = t_F = 3.0 \text{ ns}$

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5.5 \text{ V}, \text{ V}_{I} = 0 \text{ V or } \text{V}_{CC}$	>4.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance	10 MHz, $V_{CC}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CC}$	25	pF
	(Note 5)	10 MHz, $V_{CC}$ = 5.5 V, $V_{I}$ = 0 V or $V_{CC}$	30	

5.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .





A 1–MHz square input wave is recommended for propagation delay tests.

#### Figure 4. Test Circuit

#### **DEVICE ORDERING INFORMATION**

Device Order Number	Package Type	Tape and Reel Size $^{\dagger}$
NL17SZ08EDFT2G	SC-88A/SC-70-5/SOT-353 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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